New Product

MURS240 & MURS260

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifier



DO-214AA (SMB)

2.0 A 400 V, 600 V

35 A

50 ns

1.20 V

175 °C

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

IFSM

t_{rr}

 V_{F}

T_J max.

FEATURES

- Glass passivated chip junction
- · Ideal for automated placement
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMB)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MURS240	MURS260	UNIT		
Device marking codes		M2G	M2J			
Maximum repetitive peak reverse voltage	V _{RRM}	400	600	V		
Maximum average forward rectified current at T_L = 125 °C (Fig. 1)	I _{F(AV)}	2.0		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	35		А		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175		°C		



ROHS COMPLIANT

MURS240 & MURS260



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	NDITIONS	SYMBOL	MBOL MURS240 MURS260		UNIT	
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 2.0 A	T _J = 25 °C T _J = 125 °C	V _F	1.45 1.20		V	
Maximum instantaneous reverse current ⁽²⁾	rated V _R	T _J = 25 °C T _J = 125 °C	I _R	5.0 150		μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	50		ns	
Maximum reverse recovery time	I _F = 1.0 A, dl/dt = 50 A/μs, V _R = 30 V, I _{rr} = 10 % I _{RM}		t _{rr}	75		ns	
Maximum forward recovery time	I _F = 1.0 A, dl/dt = 100 A/μs, recovery to 1.0 V		t _{fr}	50		ns	

Notes:

(1) Pulse test: t_p = 300 $\mu s,$ duty cycle \leq 2 %

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MURS240	MURS260	UNIT	
Typical thermal resistance junction to lead	$R_{ ext{ heta}JL}$	15		°C/W	

Note:

(1) Units mounted on P.C.B. with 30 mm x 30 mm copper pad areas

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
MURS240-E3/52T	0.093	52T	750	7" diameter plastic tape and reel	
MURS240-E3/5BT	0.093	5BT	3200	13" diameter plastic tape and reel	
MURS240HE3/52T (1)	0.093	52T	750	7" diameter plastic tape and reel	
MURS240HE3/5BT (1)	0.093	5BT	3200	13" diameter plastic tape and reel	

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

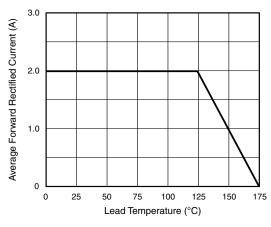


Figure 1. Forward Current Derating Curve

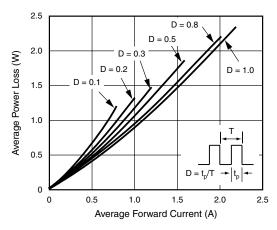


Figure 2. Forward Power Loss Characteristics



100

10

1

0.1

0

Junction Capacitance (pF)

10

1

0.1

20

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T_I = 175 °C

60

10

Percent of Rated Peak Reverse Voltage (%)

80

T_J = 25 °C

1.0 MHz V_{sig} = 50 mVp-p 100

100

T_{.1} = 100 °C

T₁ = 25 °C

40

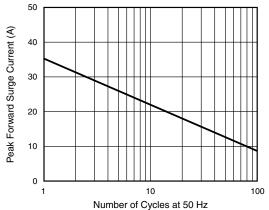


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

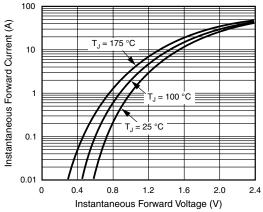
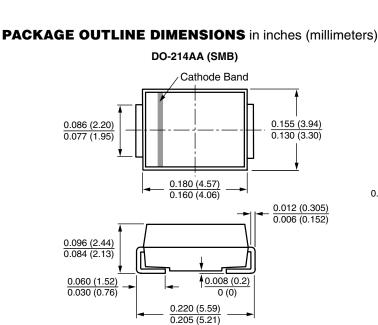
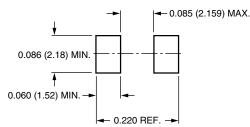


Figure 4. Typical Instantaneous Forward Characteristics



1



Instantaneous Reverse Leakage Current (μA) 0.01 0.001 Figure 5. Typical Reverse Leakage Characteristics 100

Mounting Pad Layout

Reverse Voltage (V)

Figure 6. Typical Junction Capacitance

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For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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